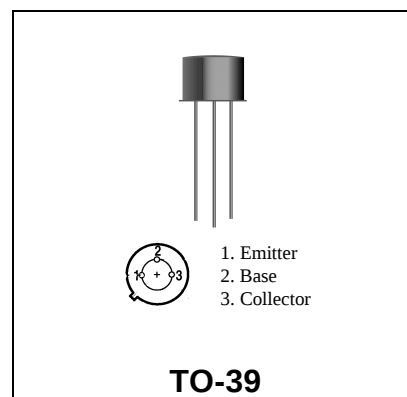


RF & MICROWAVE DISCRETE LOW POWER TRANSISTORS

Features

- Silicon NPN, To-39 packaged VHF/UHF Transistor
- Specified 400 MHz, 28Vdc Characteristics
 - Output Power = 1.0 Watt
 - Minimum Gain = 10 dB
 - Efficiency = 45%
- 800 MHz Current-Gain Bandwidth Product



DESCRIPTION:

Silicon NPN transistor, designed for VHF and UHF equipment. Applications include amplifier; pre-driver, driver, and output stages. Also suitable for oscillator and frequency-multiplier functions.

ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter	30	Vdc
V _{CBO}	Collector-Base Voltage	55	Vdc
V _{EBO}	Emitter-Base Voltage	3.5	Vdc
I _C	Collector Current	400	mA

Thermal Data

P _D	Total Device Dissipation Derate above 25°C	5.0 28.6	Watts mW/ °C
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ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

STATIC

(off)

Symbol	Test Conditions	Value			Unit
		Min.	Typ.	Max.	
BVCER	Collector-Emitter Breakdown Voltage (IC = 5.0 mAdc, RBE = 10 ohms)	55	-	-	Vdc
BVCEO	Collector-Emitter Sustaining Voltage (IC=5.0 mAdc, IB=0)	30	-	-	Vdc
BVCBO	Collector-Base Breakdown Voltage (IE = 0, IC = 0.1 mAdc)	55	-	-	Vdc
BVEBO	Emitter-Base Breakdown Voltage (IE = 0.1 mAdc, IC = 0)	3.5	-	-	Vdc
ICEO	Collector Cutoff Current (VCE = 28 Vdc, IB = 0)	-	-	20	μA
ICEX	Collector Cutoff Current (VCE = 55 Vdc, VBE = 1.5 Vdc)	-	-	100	μA

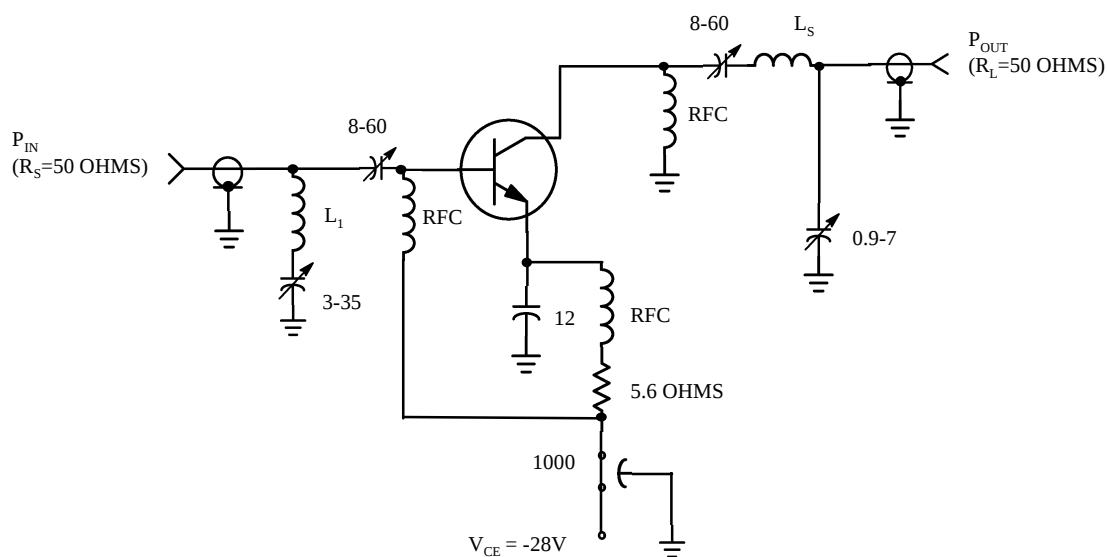
(on)

HFE	DC Current Gain				
	(IC = 360 mAdc, VCE = 5.0 Vdc) Both	5.0	-	-	-
	(IC = 50 mAdc, VCE = 5.0 Vdc) 2N3866	10	-	200	-
	(IC = 50 mAdc, VCE = 5.0 Vdc) 2N3866A	25	-	200	-
VCE(sat)	Collector-Emitter Saturation Voltage (IC = 100 mAdc, IB = 20 mAdc)	-	-	1.0	Vdc

DYNAMIC

Symbol	Test Conditions	Value			
		Min.	Typ.	Max.	Unit
f _T	Current-Gain - Bandwidth Product (IC = 50 mAdc, VCE = 15 Vdc, f = 200 MHz) 2N3866 2N3866A	500 800	800 -	- -	MHz
COB	Output Capacitance (VCB = 30 Vdc, IE = 0, f = 1.0 MHz)	-	2.8	3.5	pF

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
G _{PE}	Power Gain	Test Circuit-Figure 1 Pin = 0.1 W, VCE = 28Vdc f = 400 MHz, TC = 25 C	10	-	-	dB
P _{out}	Output Power	Test Circuit-Figure 1 Pin = 0.1 W, VCE = 28Vdc f = 400 MHz, TC = 25 C	1.0	-	-	Watts
η _c	Collector Efficiency	Test Circuit-Figure 1 Pin = 0.1 W, VCE = 28Vdc f = 400 MHz, TC = 25 C	45	-	-	%



L₁: 2 TURNS No. 18 wire, ¼" ID, 1/8" long

L_s: 2 ¾ TURNS No. 18 wire, ¼" ID, 3/16" long

Tuning capacitors are air variable

RF Low Power PA, LNA, and General Purpose Discrete Selector Guide

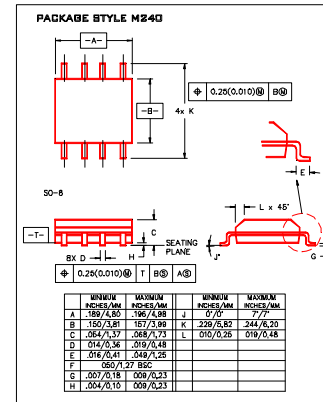
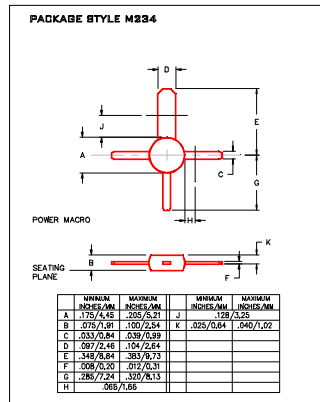
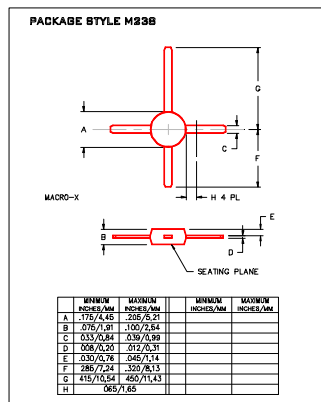
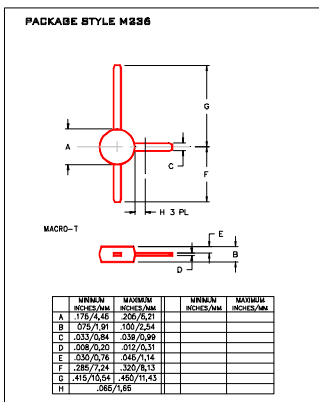
Packane	Device	Type	GPE Freq (MHz)	Pout	GPE (dB)	Efficiency (%)	GPE VCC	BVCEO	IC max (mA)
SO-8	MRF4427, R2	NPN	175	0.15	18	60	12	20	400
TO-39	2N4427	NPN	175	1	10	50	12	20	400
POWER MACRO	MRF553	NPN	175	1.5	11.5	60	12.5	16	500
POWER MACRO	MRF553T	NPN	175	1.5	11.5	50	12.5	16	500
TO-39	MRF607	NPN	175	1.75	11.5	50	12.5	16	330
TO-39	2N6255	NPN	175	3	7.8	50	12.5	18	1000
TO-72	2N5179	NPN	200		20		6	12	50
MACRO X	MRF559	NPN	512	0.5	10	65	7.5	16	150
MACRO X	MRF559	NPN	512	0.5	13	60	12.5	16	150
TO-39	2N3866A	NPN	400	1	10	45	28	30	400
SO-8	MRF3866, R1, R2	NPN	400	1	10	45	28	30	400
POWER MACRO	MRF555	NPN	470	1.5	11	50	12.5	16	400
POWER MACRO	MRF555T	NPN	470	1.5	11	50	12.5	16	400
MACRO X	MRF559	NPN	870	0.5	6.5	70	7.5	16	150
MACRO X	MRF559	NPN	870	0.5	9.5	65	12.5	16	150
SO-8	MRF8372, R1, R2	NPN	870	0.75	8	55	12.5	16	200
POWER MACRO	MRF557	NPN	870	1.5	8	55	12.5	16	400
POWER MACRO	MRF557T	NPN	870	1.5	8	55	12.5	16	400

Packag	Device	Type	Freq (MHz)	NF (dB)	NF IC (mA)	NF VCE	GNF (dB)	Gu Max (dB)	F1au (MHz)	Ccb(pF)	BVCEO	IC max (mA)
TO-39	2N5109	NPN	200	3	10	15		12	1200	3.5	20	400
TO-39	MRF5943C	NPN	200	3.4	30	15		11.4	1000		30	400
SO-8	MRF5943, R1, R2	NPN	200	3.4	30	15		15	1300		30	400
TO-72	2N5179	NPN	200	4.5	1.5	6		17	900	1	12	50
TO-72	2N2857	NPN	300	5.5	50	6		13	1600	1	15	40
TO-39	MRF517	NPN	300	7.5	50	15		5.5	4600	3	25	150
TO-72	MRF904	NPN	450	1.5	5	6		11	4000	1	15	30
TO-72	2N6304	NPN	450	5	2	5		14	1400	1	15	50
MACRO T	BFR91	NPN	500	1.9	2	5	11	16.5	5000	1	12	35
MACRO T	BFR96	NPN	500	2	10	10		14.5	500	2.6	15	100
SO-8	MRF5812, R1, R2	NPN	500	2	50	10	15.5	17.8	5000		15	200
MACRO X	MRF581A	NPN	500	2	50	10	14	15	5000		15	200
Macro	BFR90	NPN	500	2.4	2	10	15	18	5000	1	15	30
TO-72	BFY90	NPN	500	2.5	2	5		20	1300		15	50
TO-72	MRF914	NPN	500	2.5	5	10		15	4500		12	40
MACRO X	MRF581	NPN	500	2.5	50	10	15	17.8	5000		16	200
TO-39	MRF586	NPN	500	3	90	15	11	14.5	4500	2.2	17	200
MACRO X	MRF951	NPN	1000	1.3	5	6	14	17	8000	0.45	10	100
MACRO X	MRF571	NPN	1000	1.5	10	6	10		8000	1	10	70
MACRO T	BFR91	NPN	1000	2.5	2	5	8	11	5000	1	12	35
MACRO T	BFR90	NPN	1000	3	2	10	10	12.5	5000	1	15	30
TO-39	MRF545	PNP						14	1400	2	70	400
TO-39	MRF544	NPN						13.5	1500		70	400

RF (Low Power PA / General Purpose) Selection

RF (LNA / General Purpose) Selection Guide

Low Cost RF Plastic Package Options



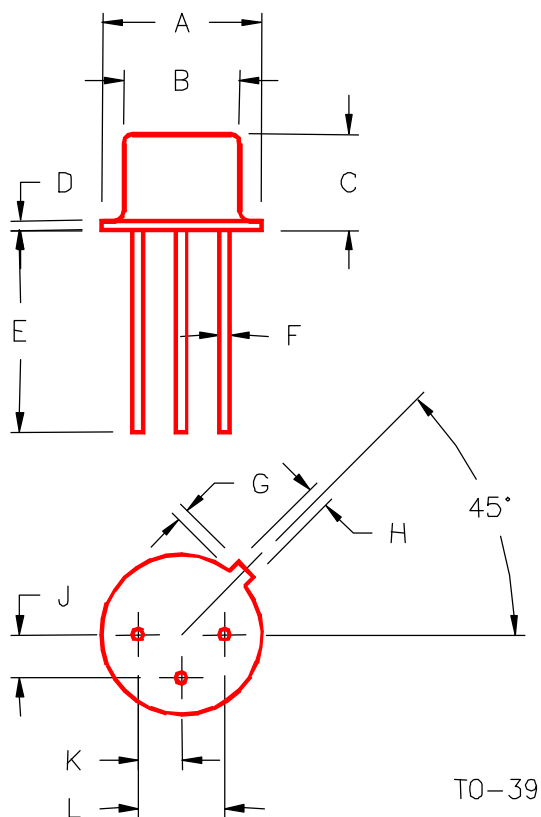
Macro T

Macro X

Power

SO-8

PACKAGE STYLE M246



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
A	.350/8,89	.370/9,40	J	.095/2,41	.105/2,67
B	.315/8,00	.335/8,51	K	.095/2,41	.105/2,67
C	.240/6,10	.260/6,60	L	.190/4,83	.210/5,33
D	.015/0,38	.045/1,14			
E	.500/12,70				
F	.016/0,41	.019/0,48			
G	.029/0,74	.040/1,02			
H	.028/0,71	.034/0,86			

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Datasheets for electronic components.